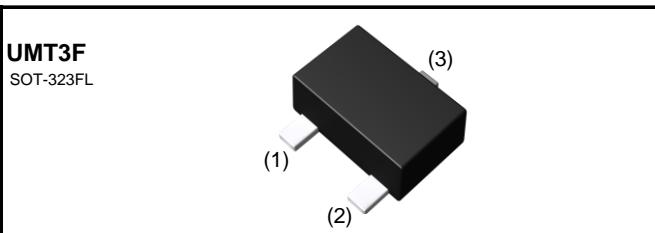


V_{DSS}	20V
$R_{DS(on)}$ (Max.)	3.5Ω
I_D	100mA
P_D	150mW

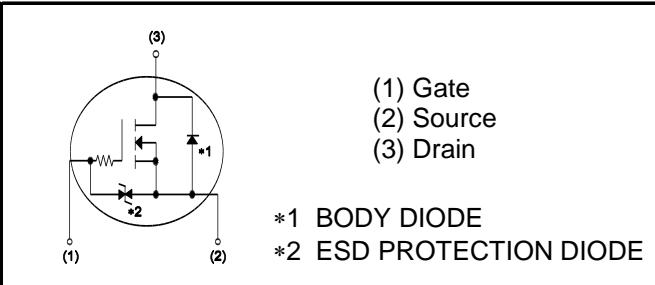
●Features

- 1) Low voltage drive(1.2V) makes this device ideal for portable equipment.
- 2) Drive circuits can be simple.
- 3) Built-in G-S Protection Diode.

●Outline



●Inner circuit



●Packaging specifications

Type	Packaging	Taping
	Reel size (mm)	180
	Tape width (mm)	8
	Basic ordering unit (pcs)	3,000
	Taping code	TL
	Marking	RW

●Absolute maximum ratings($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	20	V
Continuous drain current	I_D * ¹	± 100	mA
Pulsed drain current	$I_{D,pulse}$ * ²	± 400	mA
Gate - Source voltage	V_{GSS}	± 8	V
Power dissipation	P_D * ³	150	mW
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C

●Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - ambient	R_{thJA} * ³	-	-	833	°C/W

●Electrical characteristics($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = 1\text{mA}$	20	-	-	V
Zero gate voltage drain current	I_{DSS}	$V_{\text{DS}} = 20\text{V}, V_{\text{GS}} = 0\text{V}$	-	-	1	μA
Gate - Source leakage current	I_{GSS}	$V_{\text{GS}} = \pm 8\text{V}, V_{\text{DS}} = 0\text{V}$	-	-	± 10	μA
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = 10\text{V}, I_D = 100\text{uA}$	0.3	-	1.0	V
Static drain - source on - state resistance *4	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=4.5\text{V}, I_D=100\text{mA}$	-	2.5	3.5	Ω
		$V_{\text{GS}}=2.5\text{V}, I_D=100\text{mA}$	-	3.0	4.2	
		$V_{\text{GS}}=1.8\text{V}, I_D=50\text{mA}$	-	3.8	5.3	
		$V_{\text{GS}}=1.5\text{V}, I_D=20\text{mA}$	-	4.5	9.0	
		$V_{\text{GS}}=1.2\text{V}, I_D=10\text{mA}$	-	6.0	18.0	
		$V_{\text{GS}}=4.5\text{V}, I_D=100\text{mA}, T_j=125^\circ\text{C}$	-	4.0	5.6	
Transconductance	g_{fs} *4	$V_{\text{DS}}=10\text{V}, I_D=100\text{mA}$	180	-	-	mS

*1 Limited only by maximum temperature allowed.

*2 $P_w \leq 10\mu\text{s}$, Duty cycle $\leq 1\%$

*3 Each therminal mounted on a recommended land

*4 Pulsed

●Electrical characteristics($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	C_{iss}	$V_{GS} = 0\text{V}$ $V_{DS} = 10\text{V}$ $f = 1\text{MHz}$	-	7.1	-	pF
Output capacitance	C_{oss}		-	3.3	-	
Reverse transfer capacitance	C_{rss}		-	1.7	-	
Turn - on delay time	$t_{d(on)}^{*4}$	$V_{DD} \approx 10\text{V}, V_{GS} = 4.5\text{V}$ $I_D = 50\text{mA}$ $R_L = 200\Omega$ $R_G = 10\Omega$	-	5	-	ns
Rise time	t_r^{*4}		-	4	-	
Turn - off delay time	$t_{d(off)}^{*4}$		-	20	-	
Fall time	t_f^{*4}		-	38	-	

●Body diode electrical characteristics (Source-Drain)($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Continuous source current	I_s^{*1}	$T_c = 25^\circ\text{C}$	-	-	100	mA
Pulsed source current	I_{SM}^{*2}		-	-	400	mA
Forward voltage	V_{SD}^{*4}	$V_{GS} = 0\text{V}, I_s = 100\text{mA}$	-	-	1.2	V

● Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

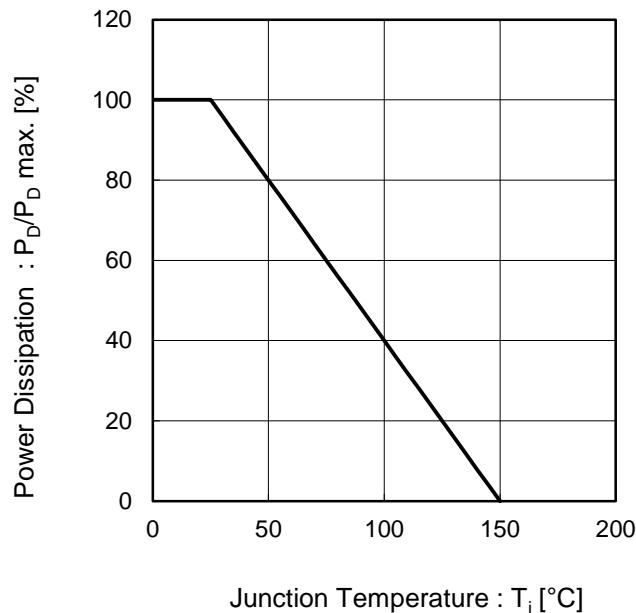


Fig.2 Drain Current Derating Curve

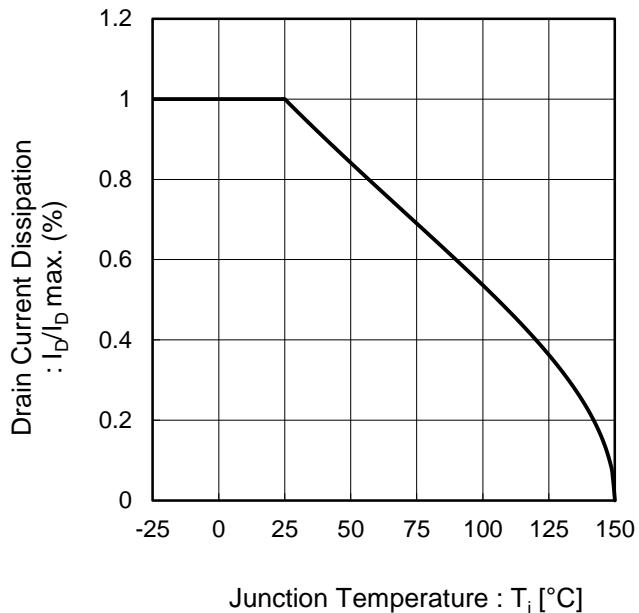


Fig.3 Typical Output Characteristics(I)

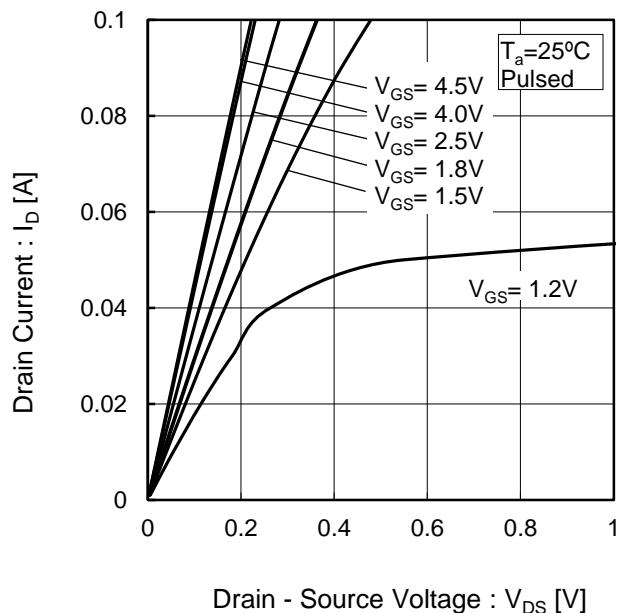
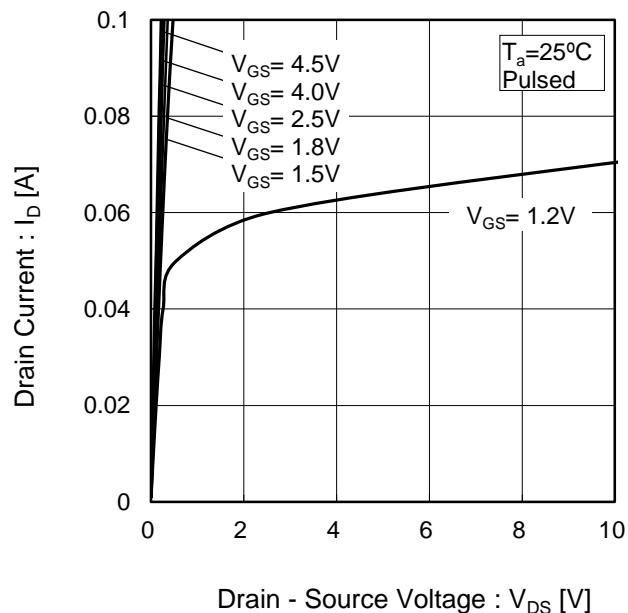


Fig.4 Typical Output Characteristics(II)



● Electrical characteristic curves

Fig.5 Breakdown Voltage
vs. Junction Temperature

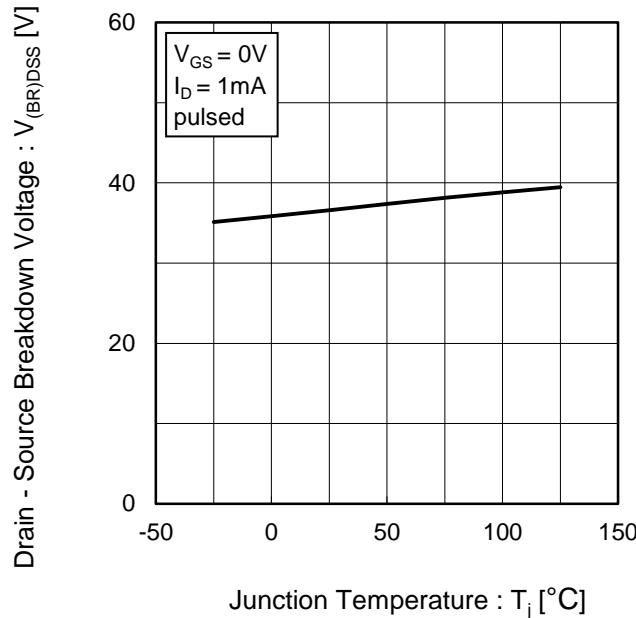


Fig.6 Typical Transfer Characteristics

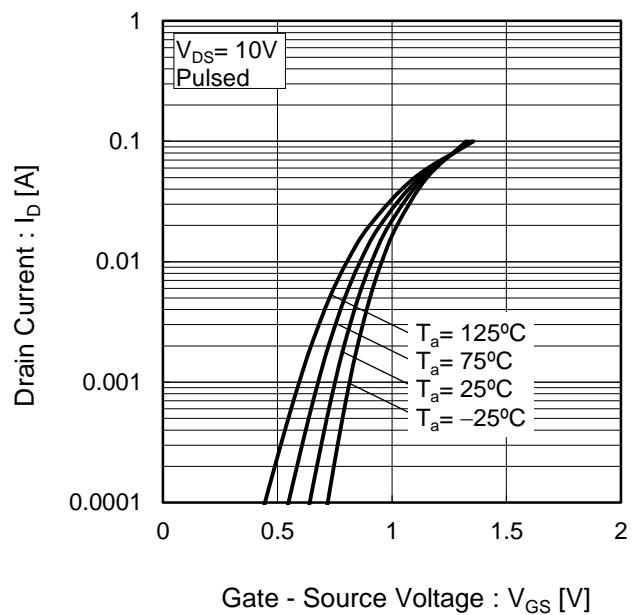


Fig.7 Gate Threshold Voltage
vs. Junction Temperature

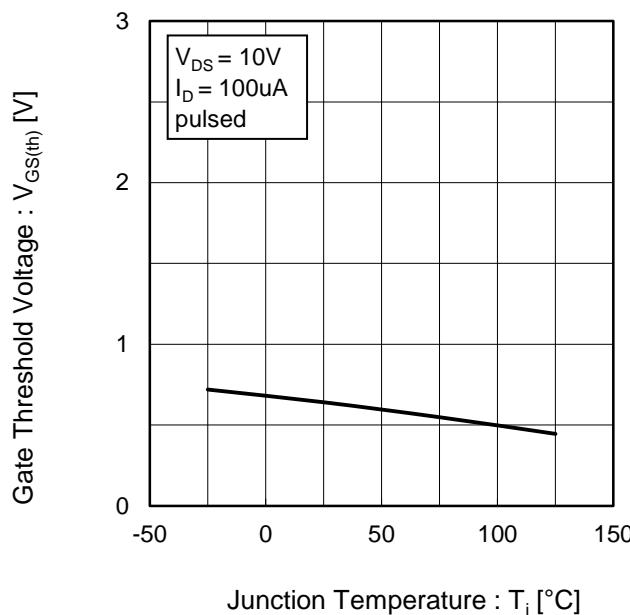
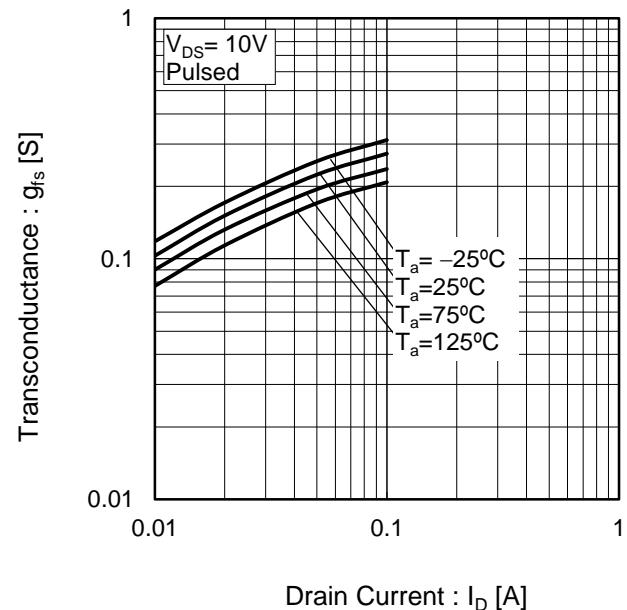


Fig.8 Transconductance vs. Drain Current



●Electrical characteristic curves

Fig.9 Static Drain - Source On - State Resistance vs. Gate Source Voltage

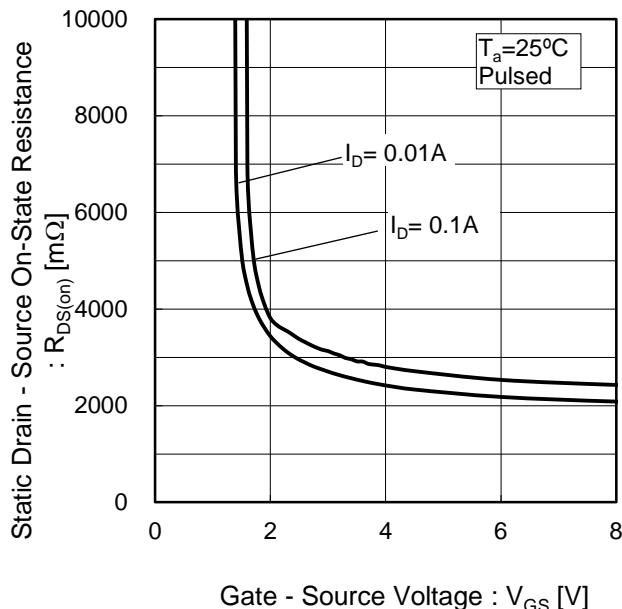


Fig.10 Static Drain - Source On - State Resistance vs. Drain Current(I_D)

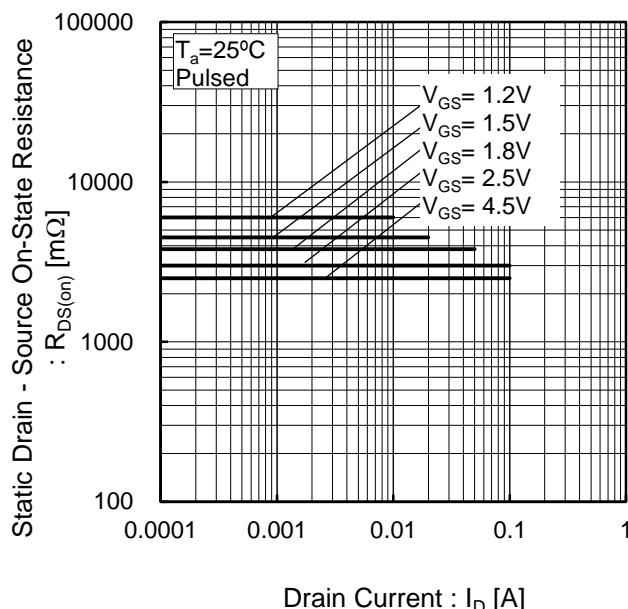


Fig.11 Static Drain - Source On - State Resistance vs. Junction Temperature

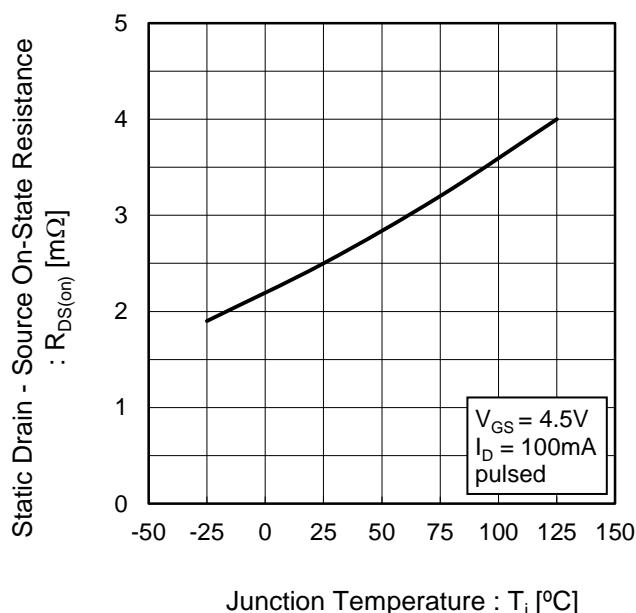
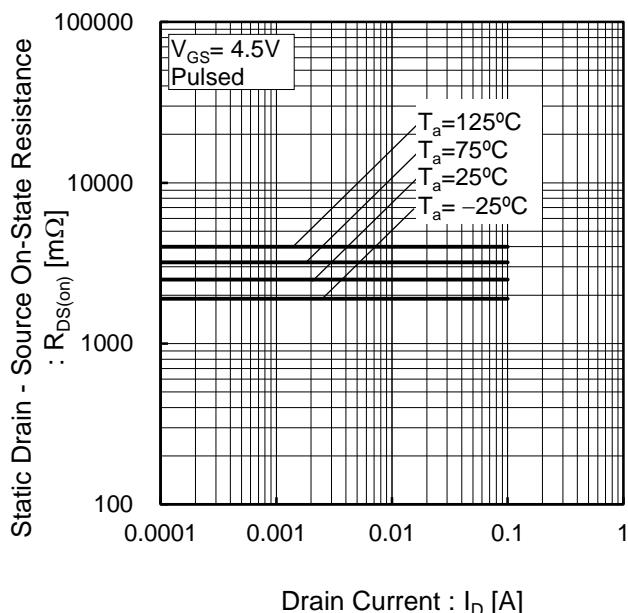
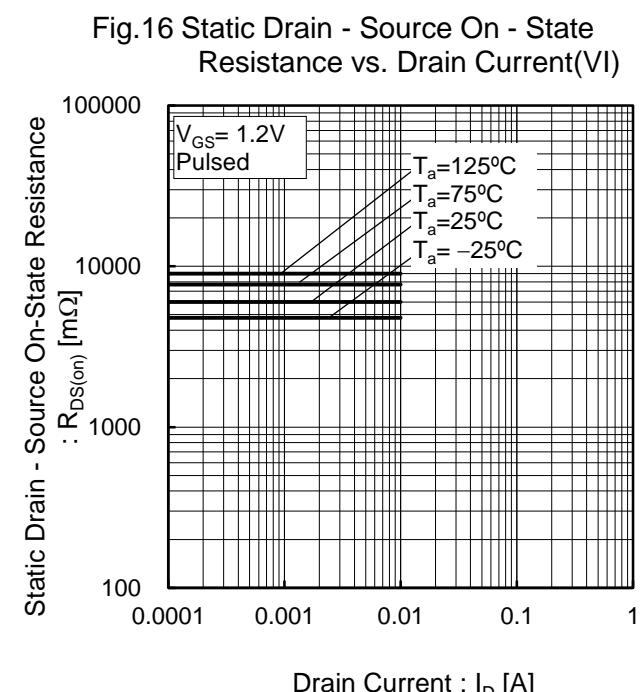
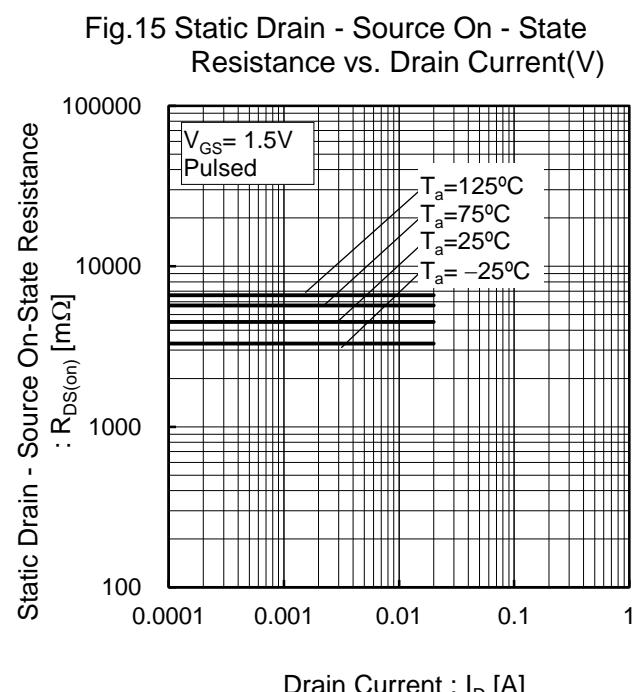
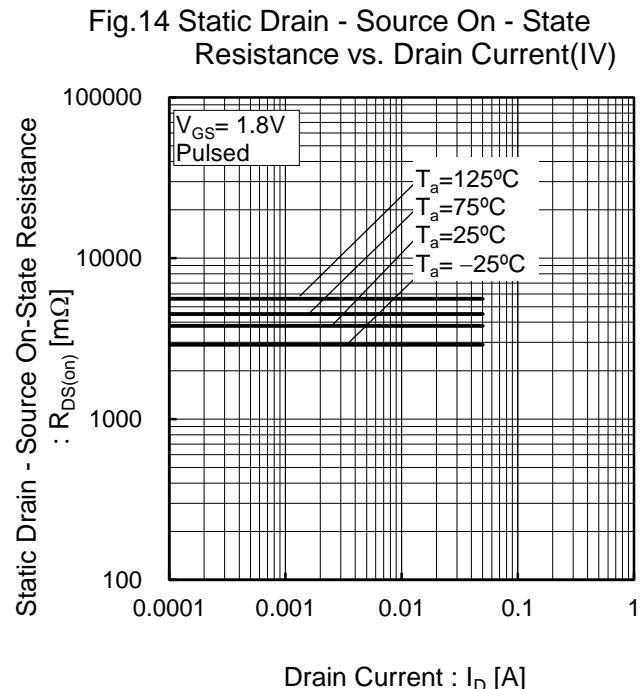
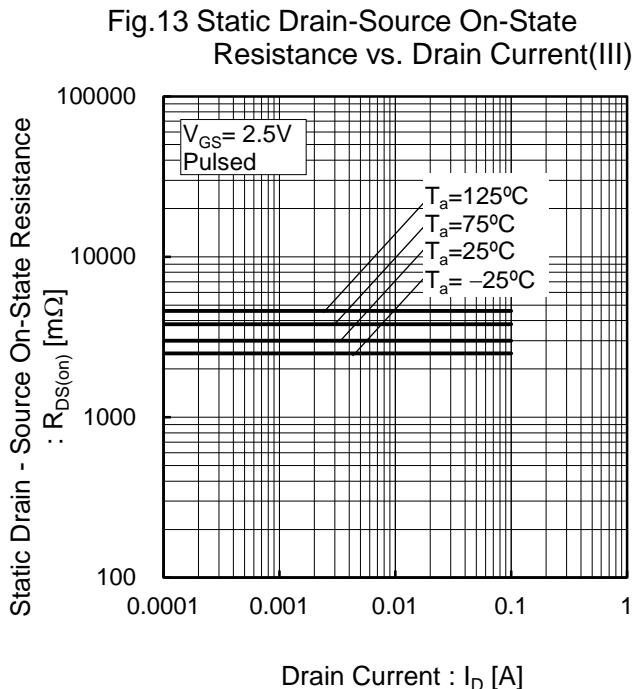


Fig.12 Static Drain - Source On - State Resistance vs. Drain Current(II)



● Electrical characteristic curves



●Electrical characteristic curves

Fig.17 Typical Capacitance vs. Drain - Source Voltage

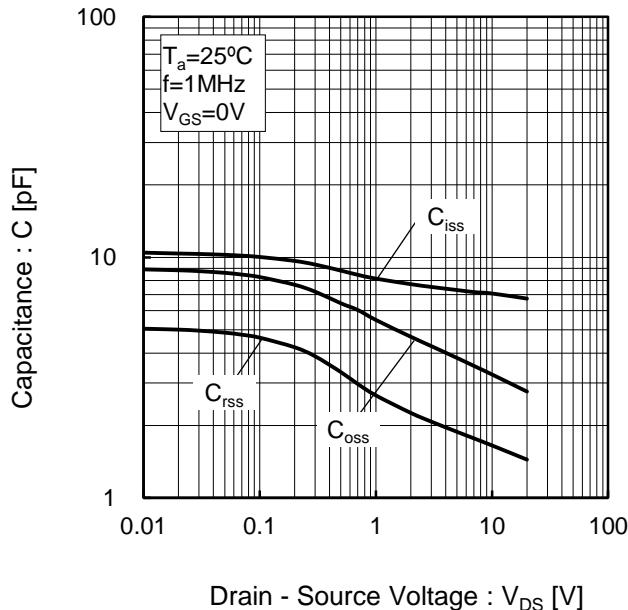


Fig.18 Switching Characteristics

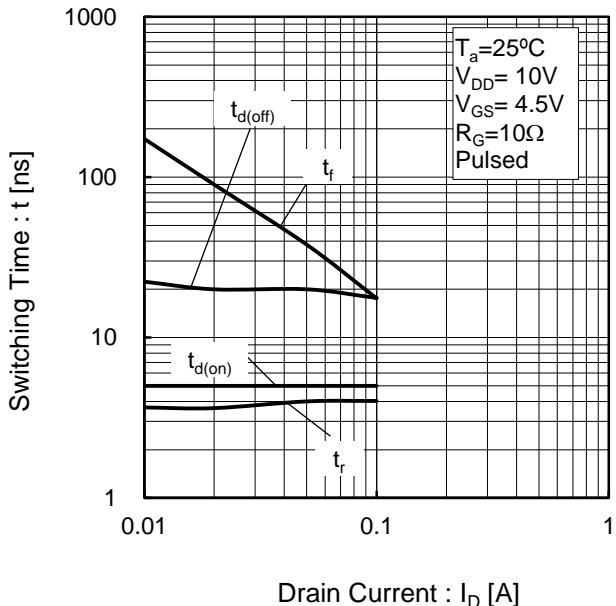
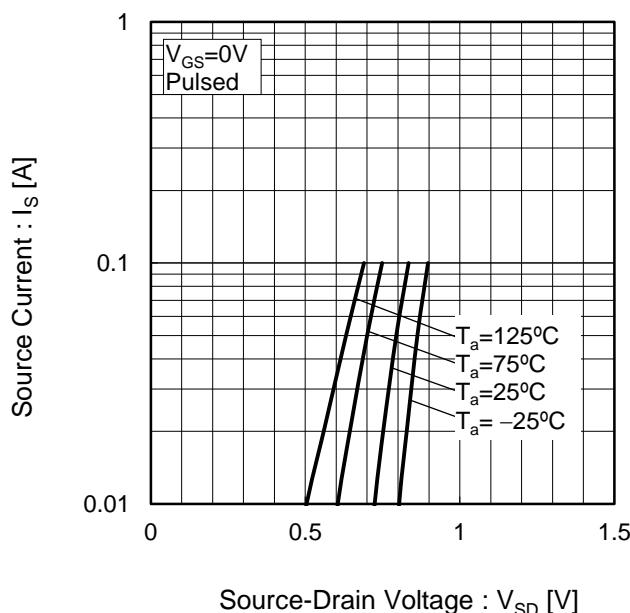


Fig.19 Source Current vs. Source Drain Voltage



●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

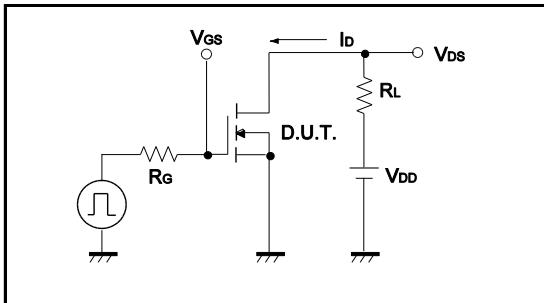
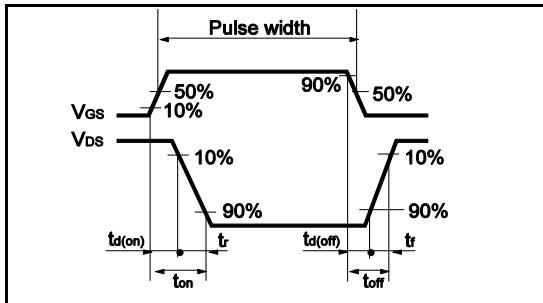


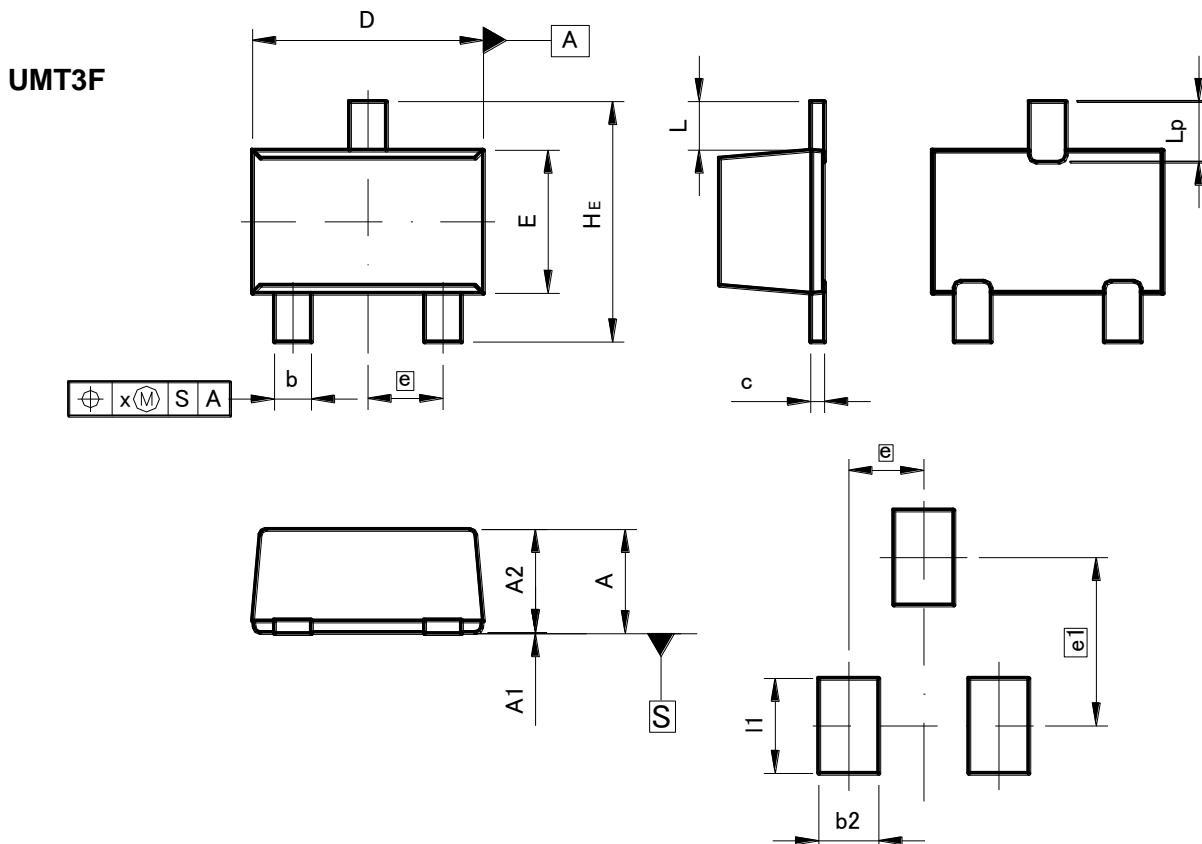
Fig.1-2 Switching Waveforms

**●Notice**

This product might cause chip aging and breakdown under the large electrified environment.

Please consider to design ESD protection circuit.

●Dimensions (Unit : mm)



Pattern of terminal position areas

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.85	1.05	0.033	0.041
A1	0.00	0.10	0	0.004
A2	0.80	1.00	0.031	0.039
b	0.27	0.42	0.011	0.017
c	0.08	0.18	0.003	0.007
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
e	0.65		0.03	
H _E	2.00	2.20	0.079	0.087
L	0.425		0.02	
L _P	0.43	0.63	0.017	0.025
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
e1	1.47		0.058	
b2	–	0.52	–	0.02
l1	–	0.83	–	0.033

Dimension in mm/inches

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